

#### Features

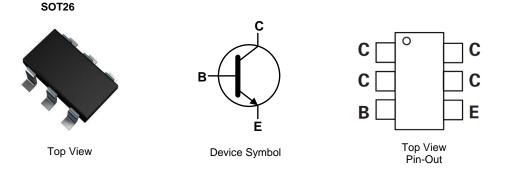
- BV<sub>CEO</sub> > 15V
- I<sub>C</sub> = 5A Continuous Collector Current
- I<sub>CM</sub> = 15A Peak Pulse Current
- $R_{CE(SAT)} = 29m\Omega$  for a Low Equivalent On-Resistance
- Very Low Saturation Voltage (70mV max @ 1A)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(1)</sup>
- Weight: 0.015 grams (Approximate)

## Applications

- DC–DC Converters
- Power Management Functions
- Power Switches
- Motor Control



#### Ordering Information (Note 4)

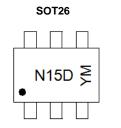
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13N15DE6TA	AEC-Q101	N15D	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>
<1000ppm antimony compounds.</li>

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



N15D = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

Date	Code	Key
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Year	2015	2	016	2017	2018	2019	2020	202	1 20	22	2023	2024	2025
Code	C		D	E	F	G	H			 J	K	L	 M
Month	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	•	1	2	3	4	5	6	7	8	9	0	N	D

and Lead-free.



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	15	V
Emitter-Base Voltage	V <sub>EBO</sub>	7.5	V
Base Current	IB	500	mA
Continuous Collector Current	Ic	5	A
Peak Pulse Collector Current	I <sub>CM</sub>	15	A

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)			W	
Linear Derating Factor	(Note 6)	– P <sub>D</sub>	1.7 13.6	mW/°C	
Thermal Desistance, Junction to Ambient	(Note 5)	D	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	73		
Thermal Resistance, Junction to Lead	(Note 7)	R <sub>θJL</sub>	18.6		
Operating and Storage Temperature Range		TJ, T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

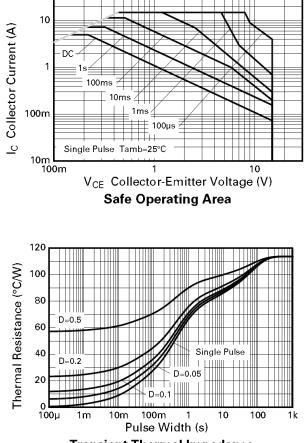
Notes: 5. For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 6, except the device is measured at t  $\leq$  5 sec.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**



Transient Thermal Impedance



1.2

1.0

0.8

0.6

0.4

0.2

0.0

0

20

40

60

80

Temperature (°C)

**Derating Curve** 

100

120

140

160

Max Power Dissipation (W)



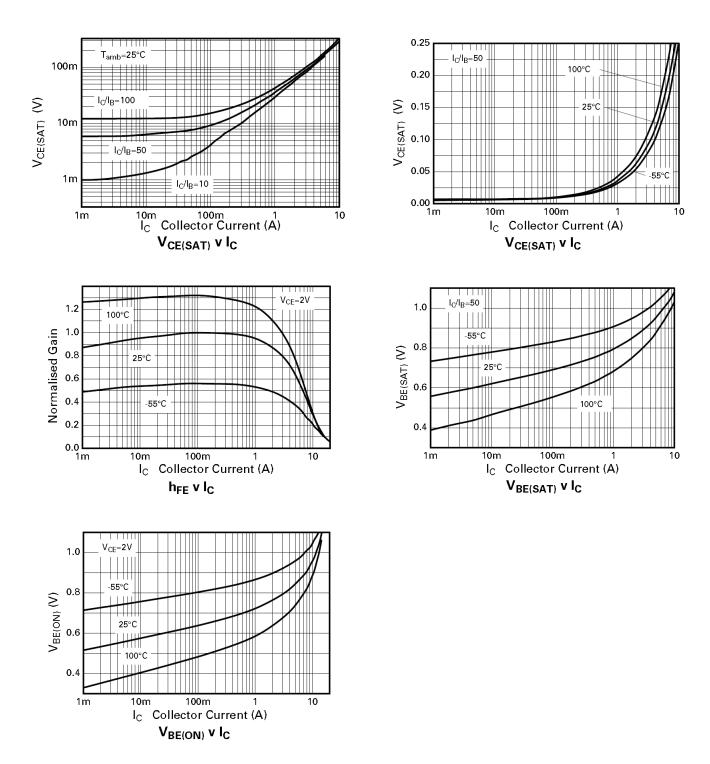
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS	•,		. 76		•	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	40	85	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	15	22	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7.5	8.5	—	V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	—	100	nA	V <sub>CB</sub> = 32V
Emitter Cutoff Current	I <sub>EBO</sub>	_	—	100	nA	$V_{EB} = 6V$
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	—	100	nA	$V_{CES} = 32V$
ON CHARACTERISTICS (Note 9)			_	-	_	
		250	400	—		$I_C = 10mA$ , $V_{CE} = 2V$
DC Current Gain	h <sub>FE</sub>	300	450	900	_	$I_C = 1A, V_{CE} = 2V$
	UFE	200	300	—		$I_C = 5A, V_{CE} = 2V$
		20	50	_		I <sub>C</sub> = 15A, V <sub>CE</sub> = 2V
		_	5	8	mV	$I_{C} = 100 \text{mA}, I_{B} = 10 \text{mA}$
Collector Emitter Seturation Voltage	N	_	45	70		$I_{\rm C} = 1$ A, $I_{\rm B} = 10$ mA
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	130	190		$I_C = 4A, I_B = 40mA$
		_	145	200		$I_{\rm C} = 5A, I_{\rm B} = 100 {\rm mA}$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	—	1	V	$I_{\rm C} = 5A, I_{\rm B} = 100 {\rm mA}$
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	_	—	0.9	V	$I_C = 5A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f <sub>T</sub>	_	72	—	MHz	$V_{CE}$ = 10V, $I_C$ = 50mA, f = 50MHz
Output Capacitance	C <sub>obo</sub>	—	76	—	pF	$V_{CB} = 10V$ , f = 1MHz
Turn-On Time	t <sub>(on)</sub>	—	92	—	ns	$V_{CC} = 10V, I_C = 3A$
Turn-Off Time	t <sub>(off)</sub>	_	340	_	ns	$I_{B1} = I_{B2} = 60 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



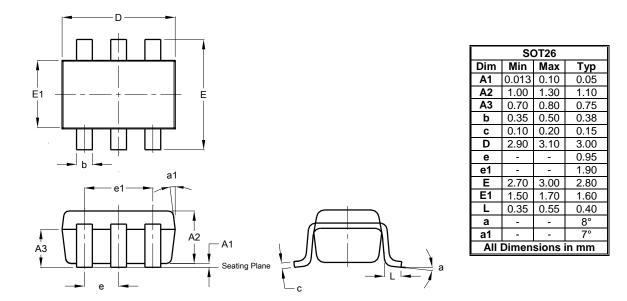
### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





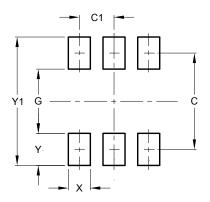
### **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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